TOSHIBA Field Effect Transistor Silicon P Channel MOS Type

SSM3J36TU

Power Management Switches

• 1.5-V drive

Low ON-resistance: R_{on} = 3.60 Ω (max) (@V_{GS} = -1.5 V)

: R_{on} = 2.70 Ω (max) (@V_{GS} = -1.8 V) : R_{on} = 1.60 Ω (max) (@V_{GS} = -2.8 V) : R_{on} = 1.31 Ω (max) (@V_{GS} = -4.5 V)

Absolute Maximum Ratings (Ta = 25 °C)

Characteristics		Symbol	Rating	Unit	
Drain-source voltage		V_{DSS}	-20	V	
Gate-source voltage		V_{GSS}	±8	V	
Drain current	DC	I _D	-330	mA	
	Pulse	I _{DP}	-660		
Drain power dissipation		P _D (Note1)	500	mW	
Drain power dissipation		P _D (Note2)	800	11100	
Channel temperature		T _{ch}	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note1: Mounted on an FR4 board

 $(25.4 \text{ mm} \times 25.4 \text{ mm} \times 1.6 \text{ mm}, \text{Cu Pad: } 645 \text{ mm}^2)$

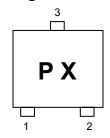
Note2: Mounted on a ceramic board.

 $(25.4 \text{ mm} \times 25.4 \text{ mm} \times 0.8 \text{ mm}, \text{Cu Pad: } 645 \text{ mm}^2)$

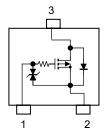
1: Gate UFM 2: Source 3: Drain Unit: mm 2: 1±0.1 1.7

Weight: 6.6 mg (typ.)

Marking



Equivalent Circuit (top view)



Handling Precaution

When handling individual devices (which are not yet mounted on a circuit board), ensure that the environment is protected against static electricity. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.

Usage Considerations

Let V_{th} be the voltage applied between gate and source that causes the drain current (I_D) to below –1 mA for the SSM3J36TU). Then, for normal switching operation, $V_{GS(on)}$ must be higher than V_{th} , and $V_{GS(off)}$ must be lower than V_{th} . This relationship can be expressed as: $V_{GS(off)} < V_{th} < V_{GS(on)}$. Take this into consideration when using the device.

Start of commercial production 2008-06

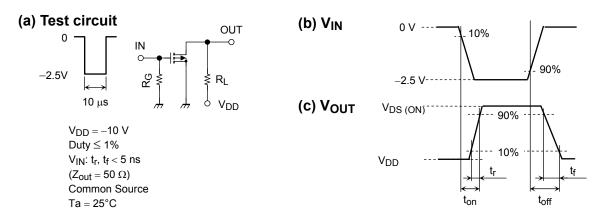


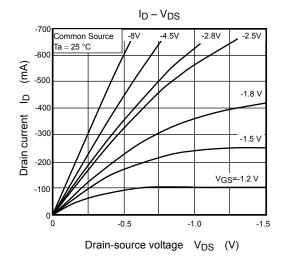
Electrical Characteristics (Ta = 25°C)

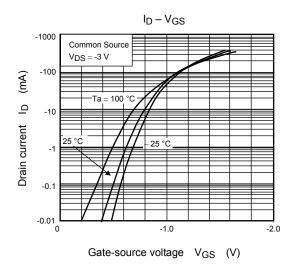
Character	ristics	Symbol	Test Conditions		Min	Тур.	Max	Unit
Drain-source breakdown voltage		V _{(BR)DSS}	$I_D = -1 \text{ mA}, V_{GS} = 0 \text{ V}$		-20			V
		V _{(BR)DSX}	$I_D = -1 \text{ mA}, V_{GS} = 8 \text{ V}$		-12			_
Drain cutoff current		I _{DSS}	$V_{DS} = -16 \text{ V}, V_{GS} = 0 \text{ V}$		_	_	-10	μΑ
Gate leakage curre	nt	I _{GSS}	$V_{GS} = \pm 8 \text{ V}, V_{DS} = 0 \text{ V}$		_		±1	μА
Gate threshold volta	age	V _{th}	$V_{DS} = -3 \text{ V}, I_{D} = -1 \text{ mA}$		-0.3	_	-1.0	٧
Forward transfer ad	Imittance	Y _{fs}	$V_{DS} = -3 \text{ V}, I_{D} = -100 \text{mA}$	(Note3)	190	_	_	mS
		R _{DS (ON)}	$I_D = -100 \text{mA}, V_{GS} = -4.5 \text{ V}$	(Note3)	_	0.95	1.31	Ω
Drain-source ON-resistance	$I_D = -80 \text{mA}, V_{GS} = -2.8 \text{ V}$		(Note3)	_	1.22	1.60		
Drain-source ON-resistance			$I_D = -40 \text{mA}, V_{GS} = -1.8 \text{ V}$	(Note3)	_	1.80	2.70	
			$I_D = -30 \text{mA}, V_{GS} = -1.5 \text{ V}$	(Note3)	_	2.23	3.60	
				_	43			
		Coss	$V_{DS} = -10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		_	10.3	_	pF
Reverse transfer capacitance		C _{rss}			_	6.1	_	
Total Gate Charge		Qg			_	1.2		
Gate-Source Charge Gate-Drain Charge		Q _{gs}	$V_{DS} = -10 \text{ V}, I_{DS} = -330 \text{mA}$	_	0.85	_	nC	
		Q _{gd}	$V_{GS} = -4 V$		_	0.35		_
Switching time	Turn-on time	t _{on}	V_{DD} = -10 V, I_{D} = -100mA V_{GS} = 0 to -2.5 V, R_{G} = 50 Ω		_	90		
	Turn-off time	t _{off}			_	200	_	ns
Drain-source forward voltage		V _{DSF}	I _D =330mA, V _{GS} = 0 V	(Note3)	_	0.88	1.2	V

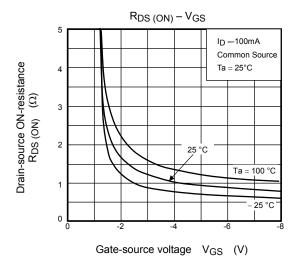
Note3: Pulse test

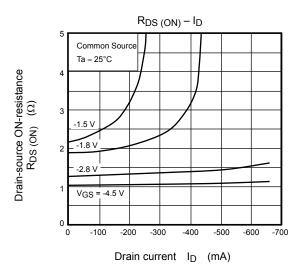
Switching Time Test Circuit

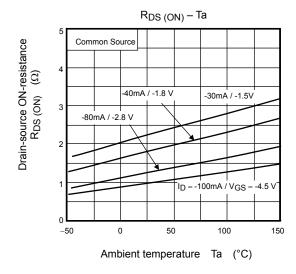


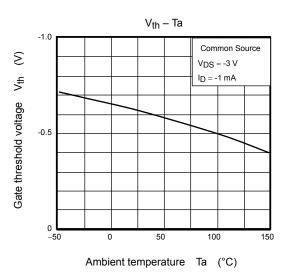


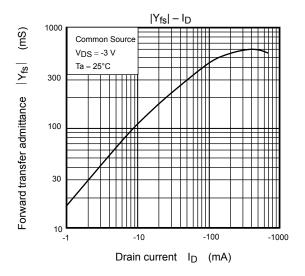


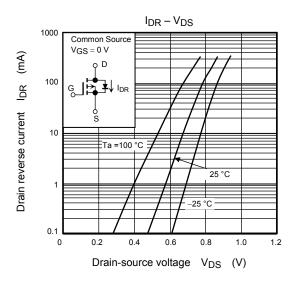


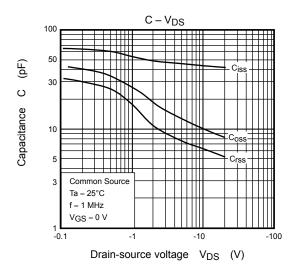


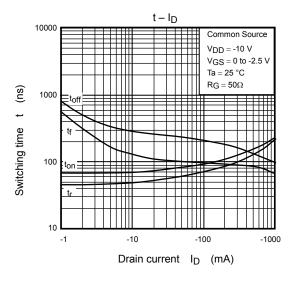


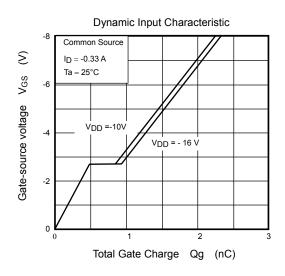


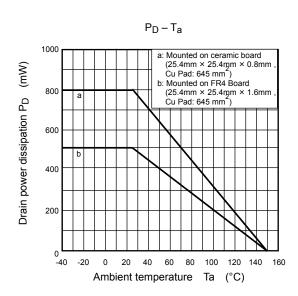












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